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July 2014

FDFMA2P853

Integrated P-Channel PowerTrench® MOSFET and Schottky Diode

General Description

This device is designed specifically as a single package solution for the battery charge switch in cellular handset and other ultra-portable applications. It features a MOSFET with low on-state resistance and an independently connected low forward voltage schottky diode for minimum conduction losses.

The MicroFET 2x2 package offers exceptional thermal performance for it's physical size and is well suited to linear mode applications.

Features

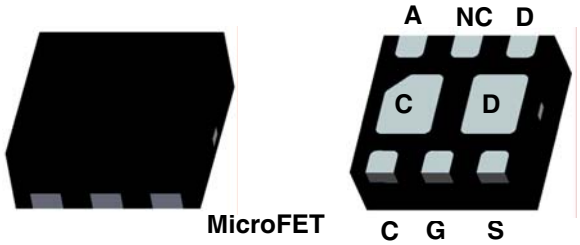
MOSFET:

- -3.0 A, -20V. $R_{DS(ON)}$ = 120 mΩ @ V_{GS} = -4.5 V
  $R_{DS(ON)}$ = 160 mΩ @ V_{GS} = -2.5 V
  $R_{DS(ON)}$ = 240 mΩ @ V_{GS} = -1.8 V

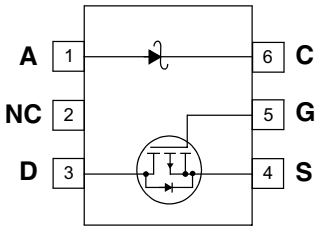
Schottky:

V_F < 0.46 V @ 500 mA

- Low Profile - 0.8 mm maximun - in the new package MicroFET 2x2 mm
- RoHS Compliant



MicroFET



Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	MOSFET Drain-Source Voltage		-20	V
V_{GSS}	MOSFET Gate-Source Voltage		±8	V
I_D	Drain Current -Continuous	(Note 1a)	-3.0	A
	-Pulsed		-6	
V_{RRM}	Schottky Repetitive Peak Reverse voltage		30	V
I_O	Schottky Average Forward Current	(Note 1a)	1	A
P_D	Power dissipation for Single Operation	(Note 1a)	1.4	W
	Power dissipation for Single Operation	(Note 1b)	0.7	
T_J, T_{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1a)	86	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1b)	173	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1c)	86	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	(Note 1d)	140	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
.853	FDFMA2P853	7inch	8mm	3000 units

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Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain–Source Breakdown Voltage	V_{GS} = 0 V, I_D = –250 μA	–20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = –250 μA, Referenced to 25°C		–12		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = –16 V, V_{GS} = 0 V			–1	μA
I_{GSS}	Gate–Body Leakage	V_{GS} = ± 8 V, V_{DS} = 0 V			±100	nA
On Characteristics (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = –250 μA	–0.4	–0.7	–1.3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = –250 μA, Referenced to 25°C		2		mV/°C
$R_{DS(on)}$	Static Drain–Source On–Resistance	V_{GS} = –4.5 V, I_D = –3.0 A V_{GS} = –2.5 V, I_D = –2.5 A V_{GS} = –1.8 V, I_D = –1.0 A V_{GS}= –4.5 V, I_D = –3.0 A, T_J=125°C		90 120 172 118	120 160 240 160	mΩ
$I_{D(on)}$	On–State Drain Current	V_{GS} = –4.5 V, V_{DS} = –5 V	–20			A
g_{FS}	Forward Transconductance	V_{DS} = –5 V, I_D = –3.0 A		7		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = –10 V, V_{GS} = 0 V, f = 1.0 MHz		435		pF
C_{oss}	Output Capacitance			80		pF
C_{rss}	Reverse Transfer Capacitance			45		pF
Switching Characteristics (Note 2)						
$t_{d(on)}$	Turn–On Delay Time	V_{DD} = –10 V, I_D = –1 A, V_{GS} = –4.5 V, R_{GEN} = 6 Ω		9	18	ns
t_r	Turn–On Rise Time			11	19	ns
$t_{d(off)}$	Turn–Off Delay Time			15	27	ns
t_f	Turn–Off Fall Time			6	12	ns
Q_g	Total Gate Charge	V_{DS} = –10 V, I_D = –3.0 A, V_{GS} = –4.5 V		4	6	nC
Q_{gs}	Gate–Source Charge			0.8		nC
Q_{gd}	Gate–Drain Charge			0.9		nC
Drain–Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain–Source Diode Forward Current				–1.1	A
V_{SD}	Drain–Source Diode Forward Voltage	V_{GS} = 0 V, I_S = –1.1 A (Note 2)		–0.8	–1.2	V
t_{rr}	Diode Reverse Recovery Time	I_F = –3.0 A, dI_F/dt = 100 A/μs		17		ns
Q_{rr}	Diode Reverse Recovery Charge			6		nC
Schottky Diode Characteristics						
I_R	Reverse Leakage	V_R = 5 V; T_J = 25°C T_J = 125°C		9.9 2.3	50 10	μA mA
I_R	Reverse Leakage	V_R = 20 V; T_J = 25°C T_J = 85°C T_J = 125°C		9.9 0.3 2.3	100 1 10	μA mA mA
V_F	Forward Voltage	I_F = 500mA; T_J = 25°C T_J = 125°C		0.4 0.3	0.46 0.35	V
V_F	Forward Voltage	I_F = 1A; T_J = 25°C T_J = 125°C		0.5 0.49	0.55 0.54	V

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Electrical Characteristics T_A = 25°C unless otherwise noted

Notes:

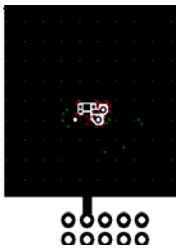
1. $R_{\theta JA}$ is determined with the device mounted on a 1 in^2 oz. copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.

(a) MOSFET $R_{\theta JA}$ = 86°C/W when mounted on a 1 in^2 pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB

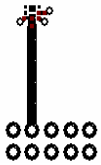
(b) MOSFET $R_{\theta JA}$ = 173°C/W when mounted on a minimum pad of 2 oz copper

(c) Schottky $R_{\theta JA}$ = 86°C/W when mounted on a 1 in^2 pad of 2 oz copper, 1.5" x 1.5" x 0.062" thick PCB

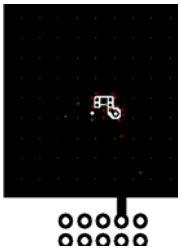
(d) Schottky $R_{\theta JA}$ = 140°C/W when mounted on a minimum pad of 2 oz copper



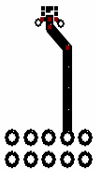
a) 86°C/W when mounted on a 1in^2 pad of 2 oz copper



b) 173°C/W when mounted on a minimum pad of 2 oz copper



c) 86°C/W when mounted on a 1in^2 pad of 2 oz copper



d) 140°C/W when mounted on a minimum pad of 2 oz copper

Scale 1: 1 on letter size paper

2. Pulse Test: Pulse Width < 300µs, Duty Cycle < 2.0%

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Typical Characteristics

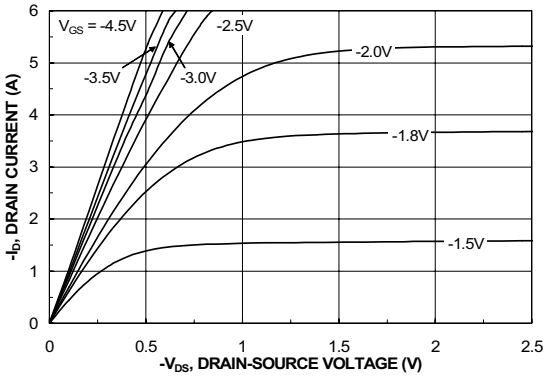

Figure 1. On-Region Characteristics

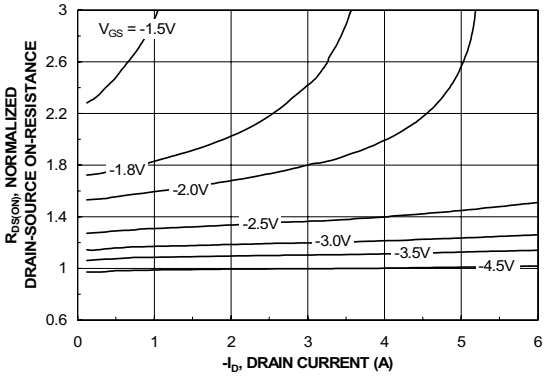

Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

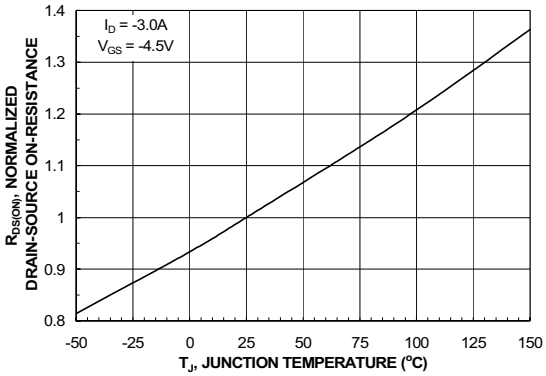

Figure 3. On-Resistance Variation with Temperature

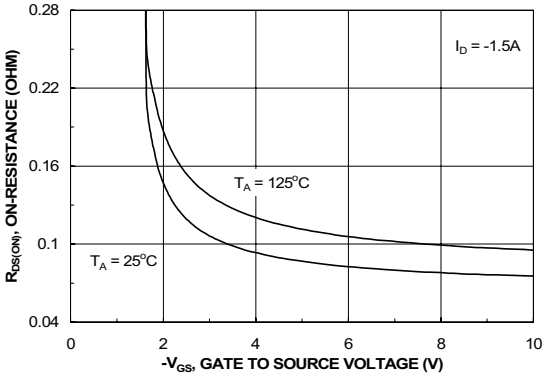

Figure 4. On-Resistance Variation with Gate-to-Source Voltage

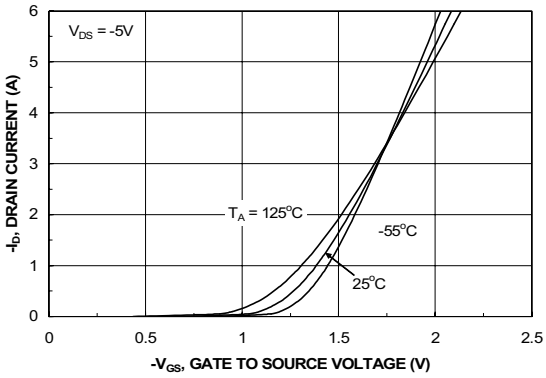

Figure 5. Transfer Characteristics

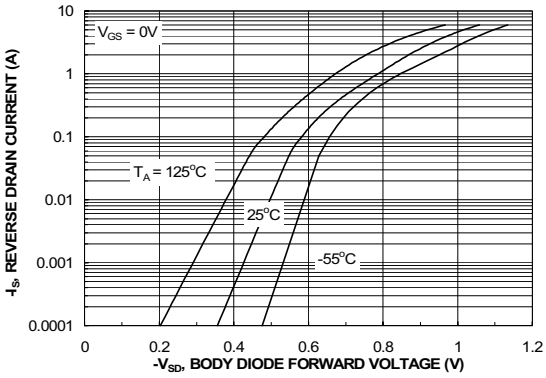

Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

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Typical Characteristics

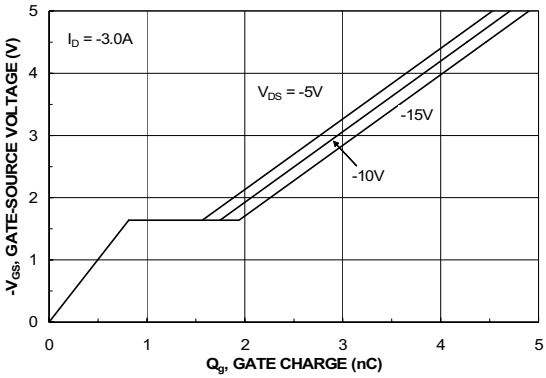

Figure 7. Gate Charge Characteristics

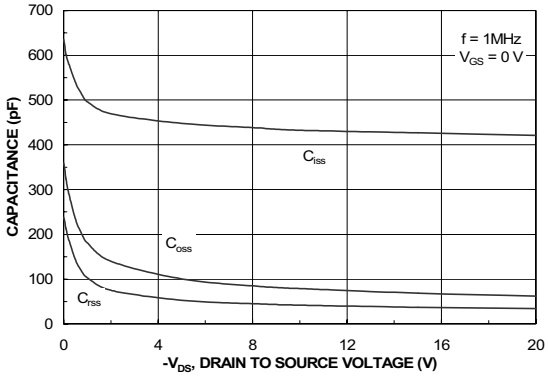

Figure 8. Capacitance Characteristics

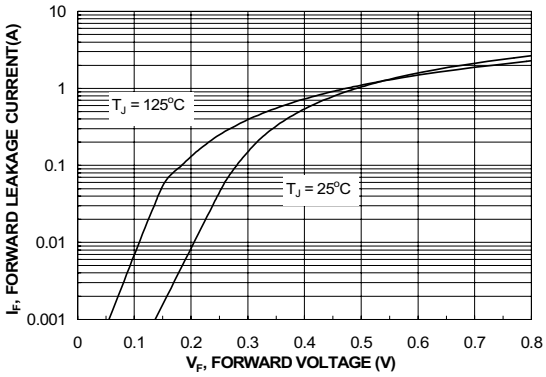

Figure 9. Schottky Diode Forward Voltage

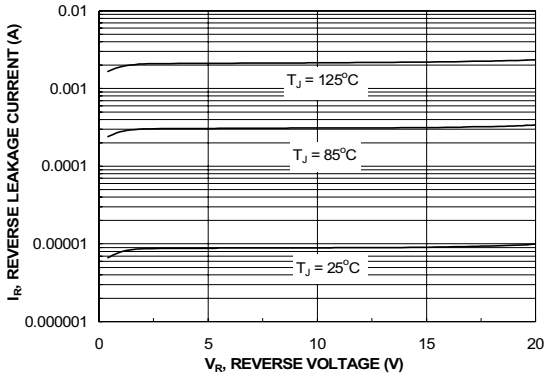

Figure 10. Schottky Diode Reverse Current

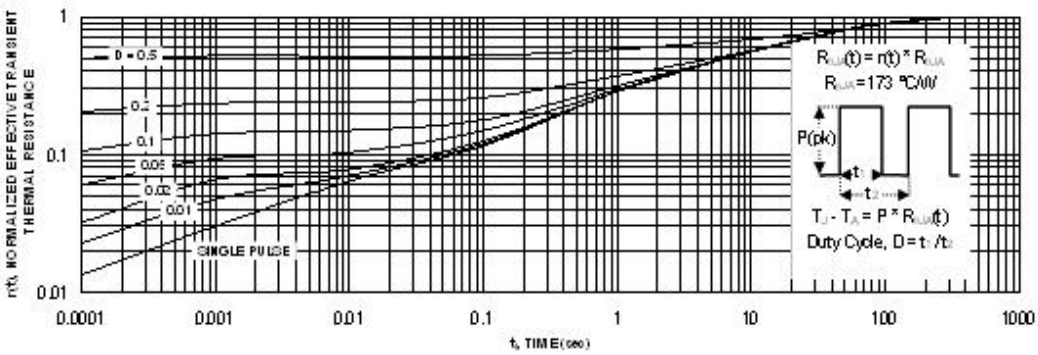

Figure 11. Transient Thermal Response Curve

Thermal characterization performed using the conditions described in Note 1c.
Transient thermal response will change depending on the circuit board design.

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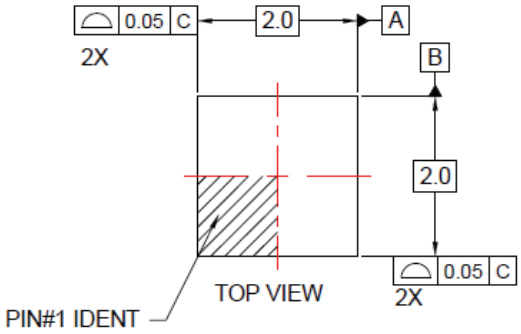
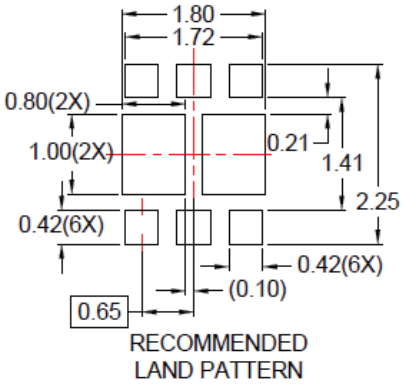
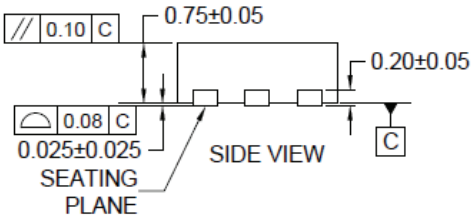
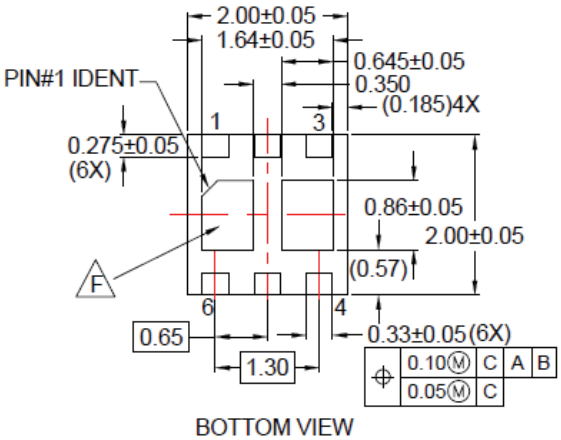
Dimensional Outline and Pad Layout









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C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.

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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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